

Typical Applications

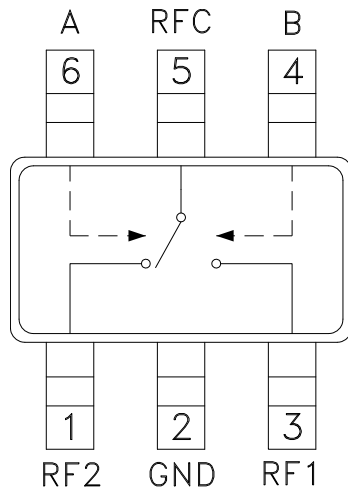
The HMC544 / HMC544E is ideal for:

- Cellular/PCS/3G Infrastructure
- Basestations & Repeaters
- WLAN, WiMAX and WiBro
- Microwave and Fixed Wireless Radios

Features

- Very Low Insertion Loss: 0.2 dB @ 1.0 GHz
- High Input P1dB: +39 dBm
- High Input IP3: +55 dBm
- Positive Control: 0/+3V to 0/+5V
- Compact SOT26 SMT Package

Functional Diagram



General Description

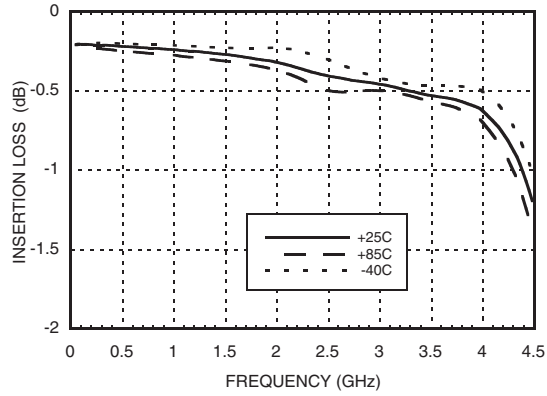
The HMC544 & HMC544E are low cost SPDT switches in 6-lead SOT26 packages for use in transmit-receive applications which require very low insertion loss at medium power levels. These devices can control signals from DC to 4.0 GHz and are especially suited for 450, 900, 1900, 2300, and 2700 MHz applications with <0.5 dB insertion loss. This GaAs PHEMT design provides exceptional linearity performance of +36 dBm 1dB compression point and +55 dBm third order intercept at +3 volt bias. RF1 and RF2 are reflective opens when "Off". On-chip circuitry allows positive control operation at very low DC current.

Electrical Specifications, $T_A = +25^\circ \text{C}$, $V_{ctl} = 0/+3 \text{Vdc}$, 50 Ohm System

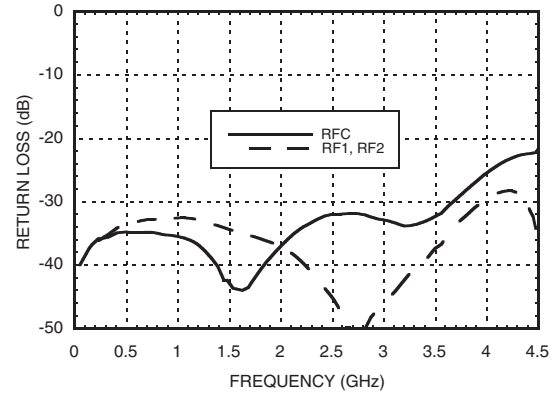
Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz		0.25	0.5	dB
	DC - 2.5 GHz		0.4	0.7	dB
	DC - 3.0 GHz		0.5	0.8	dB
	DC - 4.0 GHz		0.7	1.0	dB
Isolation	DC - 1.0 GHz	18	23		dB
	DC - 2.5 GHz	10	14		dB
	DC - 3.0 GHz	9	13		dB
	DC - 4.0 GHz	8	12		dB
Return Loss	DC - 4.0 GHz		32		dB
Input Power for 1 dB Compression	0.3 - 4.0 GHz	0/+5V Control	36	39	dBm
		0/+3V Control	33	36	dBm
Input Third Order Intercept (Two-Tone Input Power = +27 dBm Each Tone)	0.3 - 4.0 GHz		55		dBm
Switching Characteristics	DC - 4.0 GHz	tRISE, tFALL (10/90% RF)	70		ns
		tON, tOFF (50% CTL to 10/90% RF)	140		ns

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

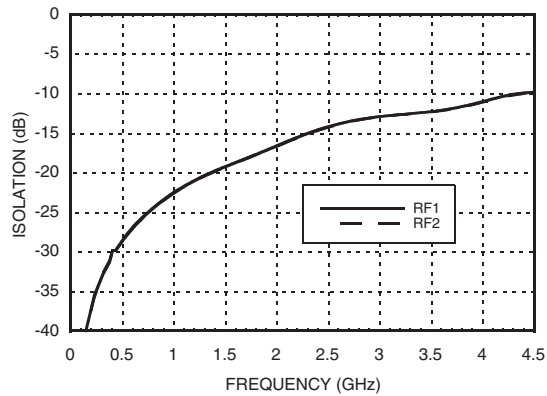
Insertion Loss



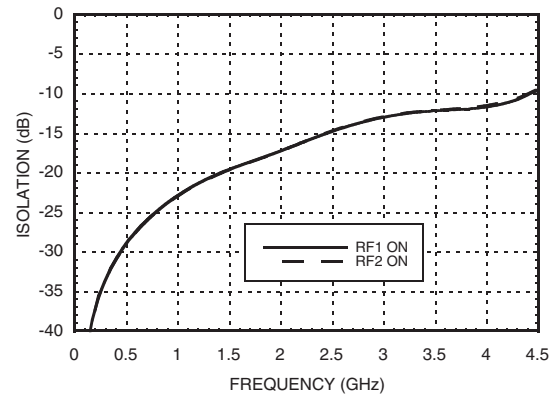
Return Loss



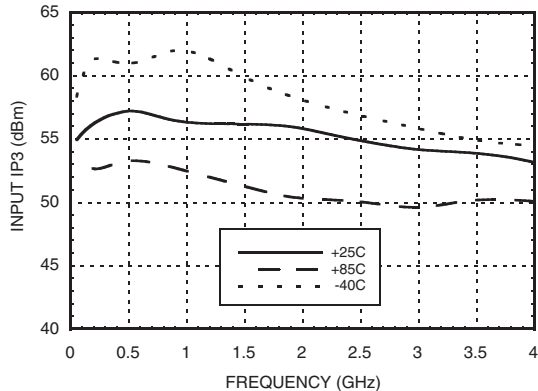
Isolation Between Ports RFC & RF1 / RF2



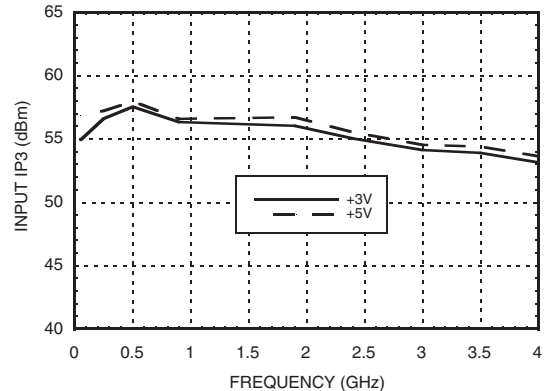
Isolation Between Ports RF1 & RF2



Input IP3 vs. Temperature, Vctl = 0/+3V

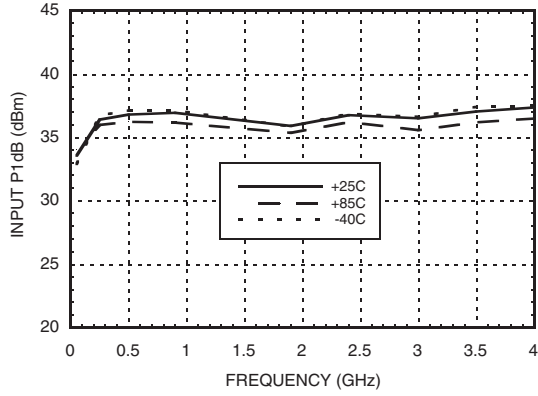


Input IP3 vs. Vctl

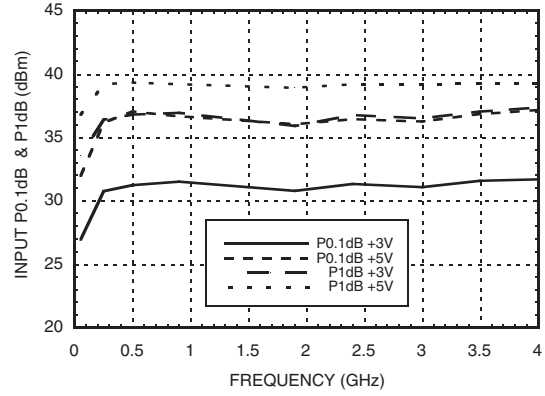




Input P1dB vs. Temperature, Vctl = 0/+3V



Compression vs. Vctl



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SWITCHES - SMT

Truth Table

Control Input		Signal Path	
A	B	RFC to RF1	RFC to RF2
Low	High	On	Off
High	Low	Off	On

Control Voltages

State	Bias Condition
Low	0 to 0.2 Vdc @ 1 μ A Typical
High	+3 Vdc @ 0.5 μ A Typical to +5 Vdc @ 2 μ A Typical (\pm 0.2 Vdc)

Absolute Maximum Ratings

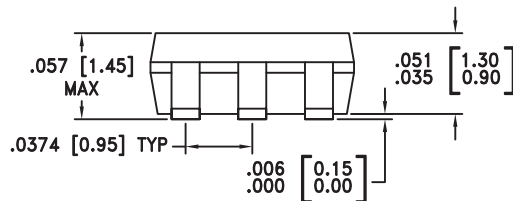
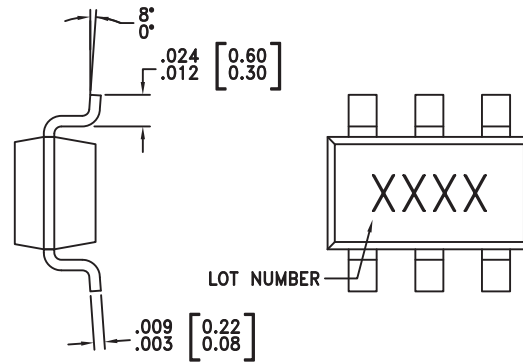
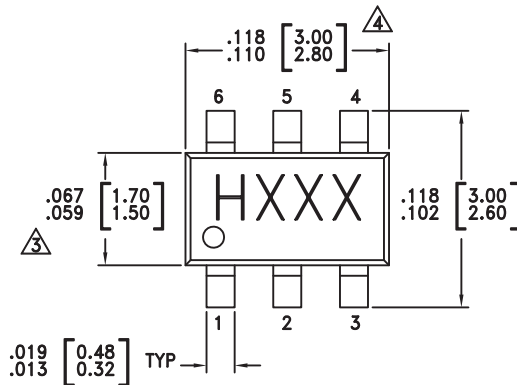
RF Input Power (Vctl = 0/+5V)	+39 dBm
Control Voltage Range (A & B)	-0.2 to +12 Vdc
Hot Switch Power Level (Vctl = 0/+5V)	+39 dBm
Channel Temperature	150 °C
Continuous P _{diss} (T= 85 °C) (derate 7.14 mW/ °C above 85°C)	0.465 W
Thermal Resistance	140 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

DC blocks are required at ports RFC, RF1 and RF2.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
- △ DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- △ DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC544	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H544 XXXX
HMC544E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	544E XXXX

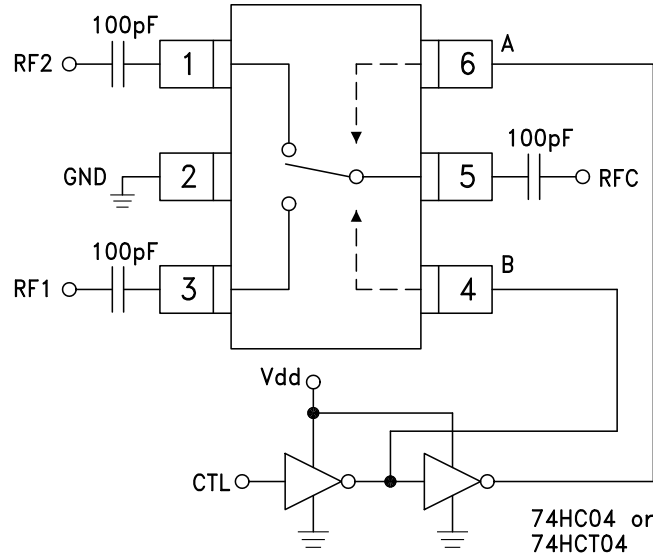
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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
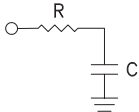
Typical Application Circuit



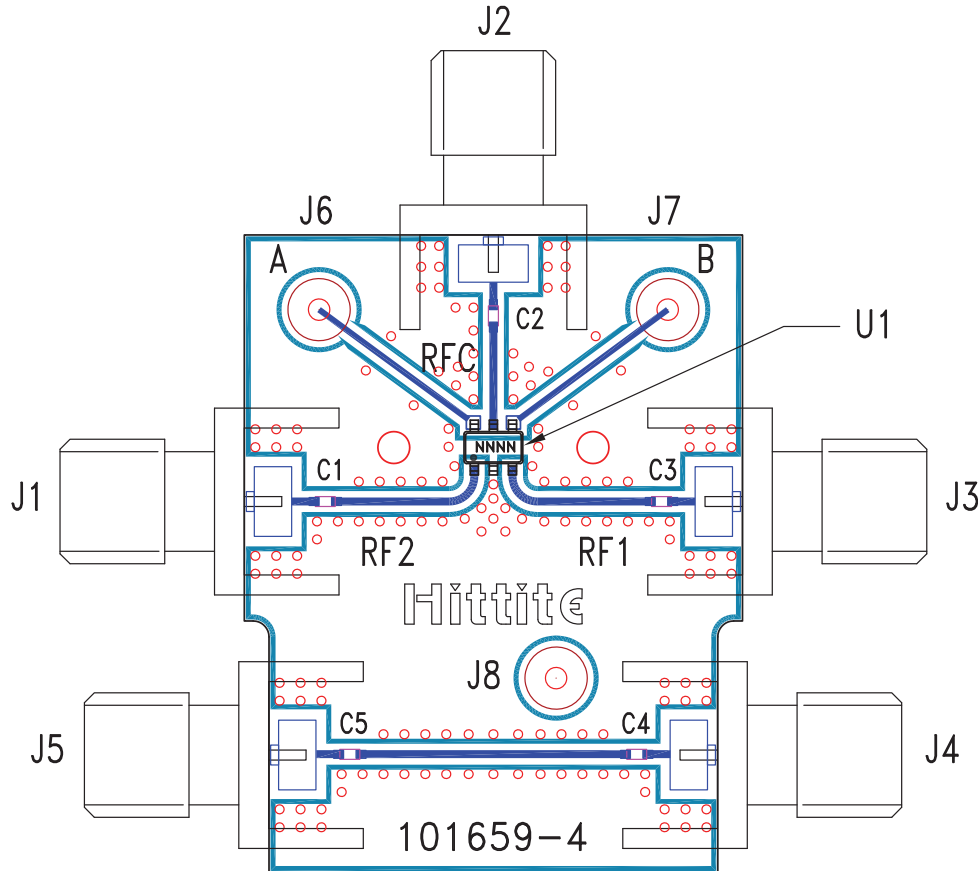
Notes:

1. Set logic gate Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of +3V to +5V applied to the CMOS logic gates.
3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 5	RF2, RF1, RFC	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
2	GND	This pin must be connected to RF/DC ground.	
4	B	See truth and control voltage tables.	
6	A	See truth and control voltage tables.	

Evaluation Circuit Board



List of Materials for Evaluation PCB 101675 ^[1]

Item	Description
J1 - J5	PCB Mount SMA RF Connector
J6 - J8	DC Pin
C1 - C5	330 pF capacitor, 0402 Pkg.
U1	HMC544 / HMC544E SPDT Switch
PCB ^[2]	101659 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.